



## SMBYW02-200

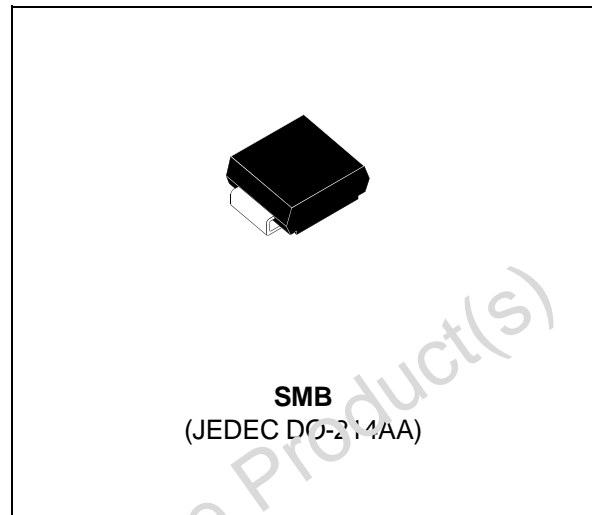
### HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

#### MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	<b>2 A</b>
$V_{RRM}$	<b>200 V</b>
$V_F(max)$	<b>0.85 V</b>
$T_j(max)$	<b>150 °C</b>

#### FEATURES AND BENEFITS

- SUITED FOR SMPS
- VERY LOW CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- HIGH SURGE CURRENT CAPABILITY
- LOW FORWARD AND REVERSE RECOVERY TIMES



#### DESCRIPTION

Single chip rectifier suited for Switch Mode Power Supplies and high frequency DC to DC converters. Packaged in SMB, this surface mount device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

#### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	200	V
$I_{F(RMS)}$	RMS forward current	10	A
$I_{F(AV)}$	Average forward current	2	A
		$T_I=100^{\circ}C$ $\delta = 0.5$	
$I_{FSM}$	Non repetitive surge peak forward current	50	A
		$t_p=10ms$ sinusoidal	
$T_{stg}$	Storage temperature range	- 65 to + 150	°C
$T_j$	Maximum operating junction temperature	150	°C

## SMBYW02-200

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth (j-l)	Junction to leads	25	°C/W

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameters	Test Conditions		Min.	Typ.	Max.	Unit
V <sub>F</sub> *	Reverse Leakage Current	T <sub>j</sub> = 25°C	I <sub>F</sub> = 6 A			1.25	V
		T <sub>j</sub> = 100°C	I <sub>F</sub> = 2 A		0.8	0.85	
I <sub>R</sub> **	Forward Voltage Drop	T <sub>j</sub> = 25°C	V <sub>R</sub> = V <sub>RRM</sub>			10	μA
		T <sub>j</sub> = 100°C			0.1	0.3	mA

Pulse test : \* tp = 380 μs, δ < 2 %

\*\* tp = 5 ms, δ < 2 %

To evaluate the conduction losses use the following equation :

$$P = 0.7 \times I_{F(AV)} + 0.075 \times I_{F(RMS)}^2$$

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
trr	T <sub>j</sub> = 25°C	I <sub>F</sub> = 1 A    di <sub>F</sub> /dt = -50A/μs    V <sub>R</sub> = 30V		26	35	ns
tfr	T <sub>j</sub> = 25°C	I <sub>F</sub> = 2 A    di <sub>F</sub> /dt = -50A/μs V <sub>FR</sub> = 1.1 x V <sub>F</sub> max		30		ns
V <sub>FP</sub>	T <sub>j</sub> = 25°C	I <sub>F</sub> = 2 A    di <sub>F</sub> /dt = -50A/μs		5		V

Fig. 1: Low frequency power losses versus average current.

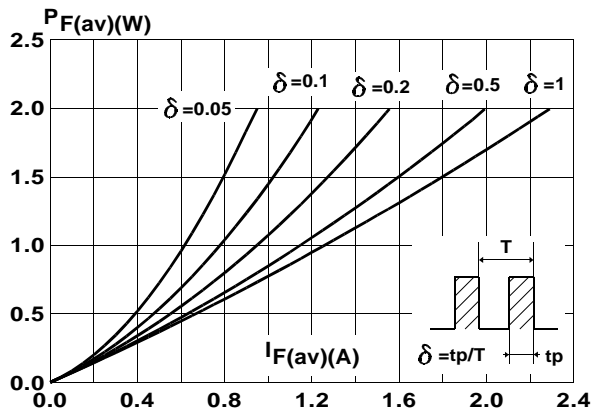


Fig. 2: Peak current versus form factor.

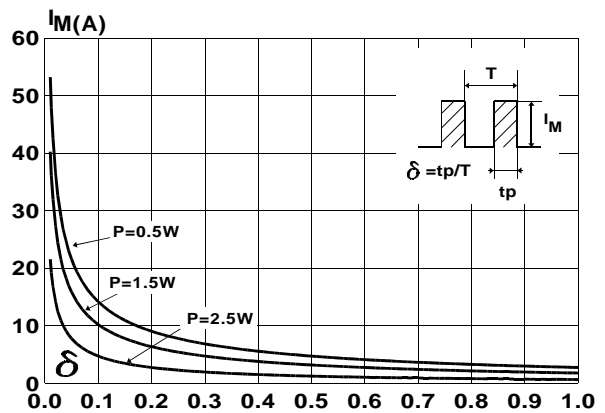


Fig. 3: Non repetitive surge peak forward current versus overload duration.

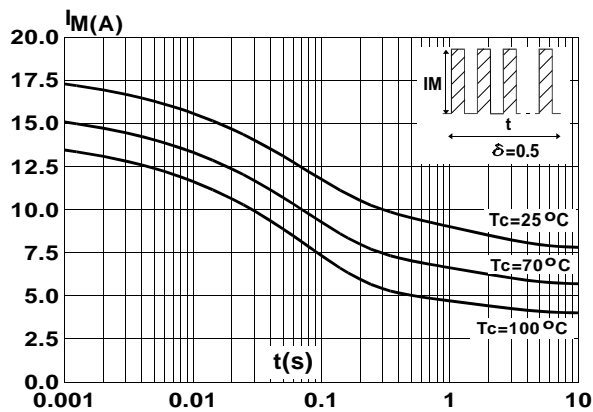


Fig. 4: Relative variation of thermal impedance junction to lead versus pulse duration.

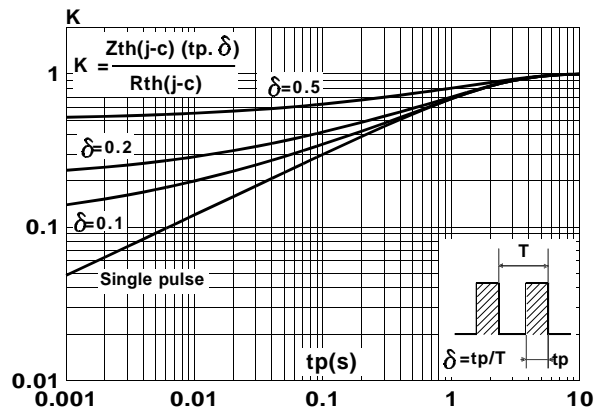


Fig. 5: Voltage drop versus forward current (maximum values).

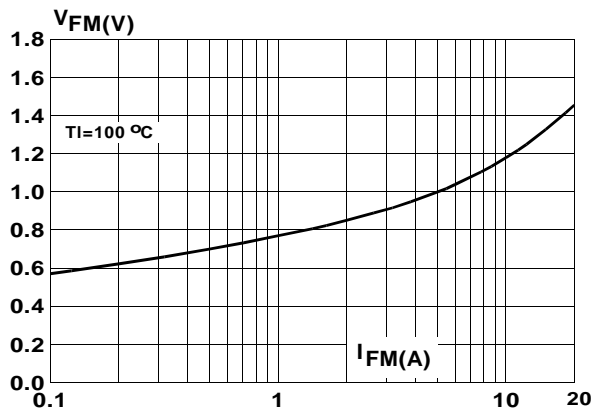


Fig. 6: Average current versus ambient temperature (delta=0.5).

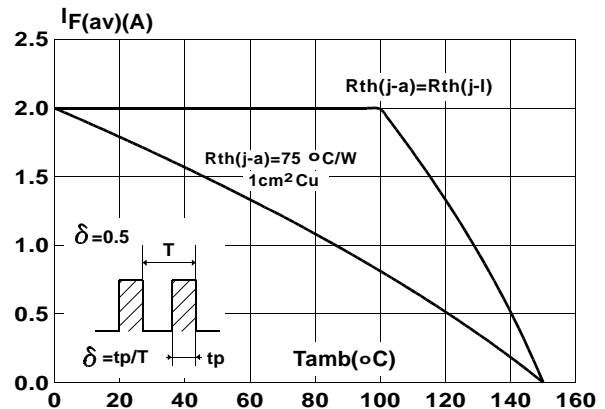


Fig. 7: Capacitance versus reverse voltage applied.

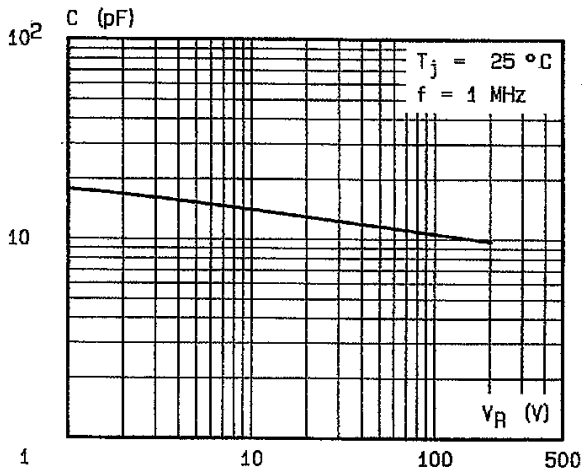


Fig. 9: Peak reverse current versus  $di_F/dt$ .

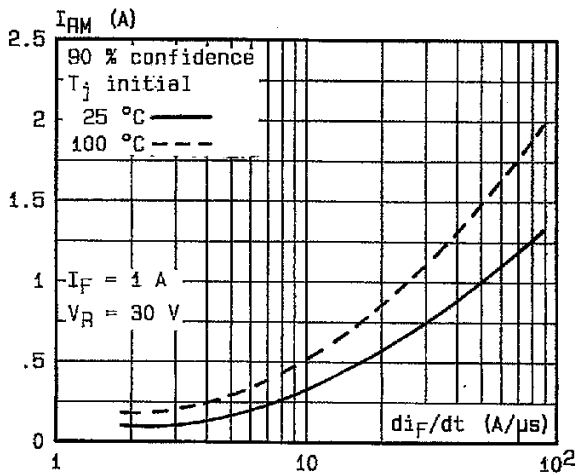


Fig. 11: Thermal resistance junction to ambient versus copper surface under each lead.

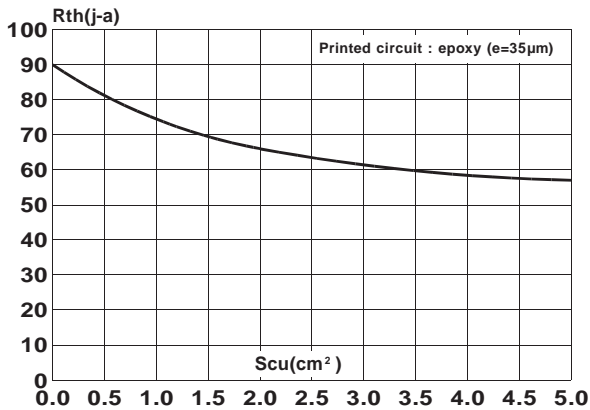


Fig. 8: Recovery time versus  $di_F/dt$ .

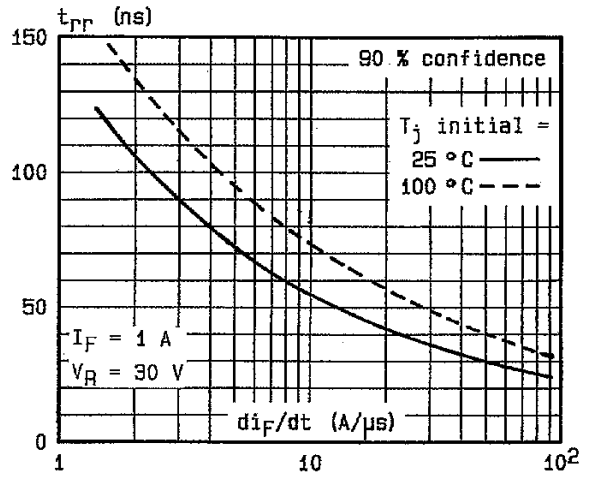
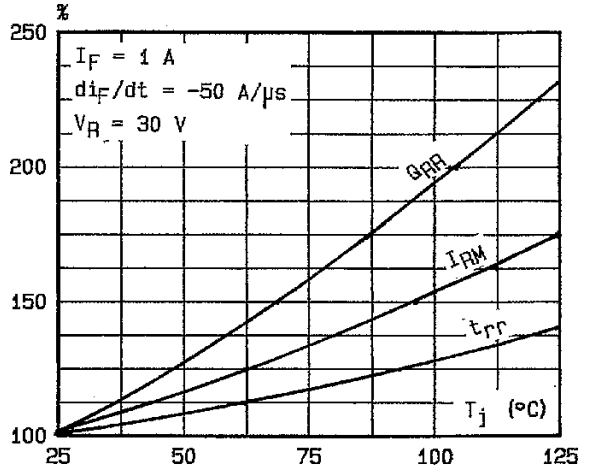
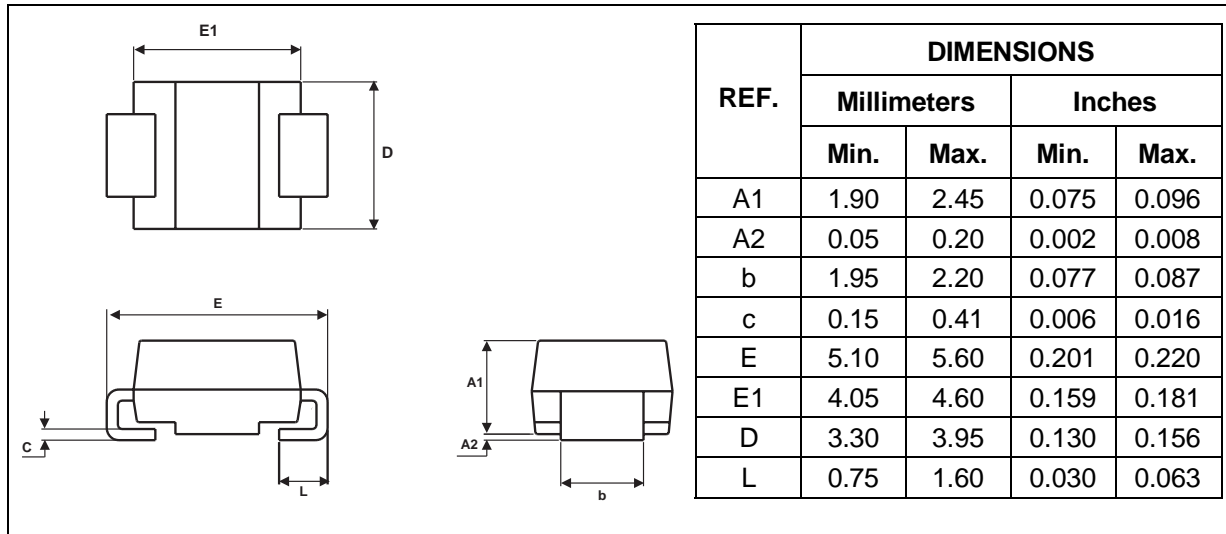


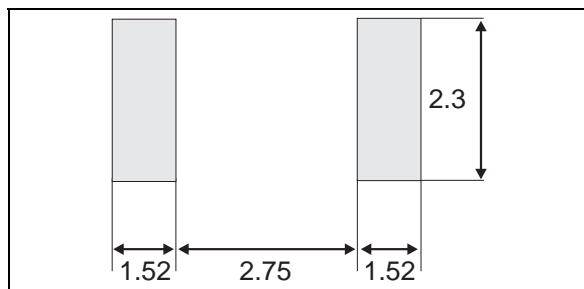
Fig. 10: Dynamic parameters versus junction temperature.



**PACKAGE MECHANICAL DATA**  
SMB



**FOOTPRINT DIMENSIONS (in millimeters)**  
SMB



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
SMBYW02-200	A20	SMB	0.11g	2500	Tape & reel

- Band indicates cathode
- Epoxy meets UL94,V0

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